

LISTING OF CLAIMS

The following listing of claims replaces all previous versions, and listings, of claims in the present application.

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1. (Currently amended) A physical quantity detection device comprising:
an operational amplifier;
a first resistor connected between an inverting input of said operational amplifier and a first reference potential;
a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;
a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance; and
a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, and wherein said reference voltage generation circuit sets said reference voltage to a middle potential between said first potential and said second reference potential ~~includes third and fourth resistors connected in series between said first and second reference potentials to generate a divided voltage as said reference voltage, and wherein a temperature coefficient of resistance of said third resistor is substantially equal to a temperature coefficient of resistance of said fourth resistor so that said reference voltage can be kept constant irrespective of temperature variation.~~
2. (Previously amended) The physical quantity detection device as claimed in claim 1, wherein each of said first and second resistors and said feedback resistor comprises a diffused resistor and a concentration of impurity of said feedback resistor is different from concentrations of impurity of said first and second resistors.
3. (Original) The physical quantity detection device as claimed in claim 2, wherein said concentrations of impurity of said first and second resistors are from $0.4 \times 10^{19} \text{ cm}^{-3}$ to $8 \times 10^{19} \text{ cm}^{-3}$ and said concentration of impurity of said feedback resistor is from $1.6 \times 10^{17} \text{ cm}^{-3}$ to $7 \times 10^{17} \text{ cm}^{-3}$.
4. (Original) The physical quantity detection device as claimed in claim 1, wherein one of said first and second resistors comprises said sensing element of which resistance varies on the basis of said physical quantity, and a resistance of the other of said first and second resistors remains constant with respect to said physical quantity.

5. (Canceled)

6. (Previously amended) The physical quantity detection device as claimed in claim 1, wherein one of said third and fourth resistors has a trimming structure to trim said reference voltage toward an output voltage of said operational amplifier on when said physical quantity is zero.

7.(Currently amended) ~~The~~ A physical quantity detection device ~~as claimed in claim 1,~~ further comprising:

an operational amplifier;

a first resistor connected between an inverting input of said operational amplifier and a first reference potential;

a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;

a first feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance;

a second feedback resistor having a trimming structure connected in parallel with said first feedback resistor; and

a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, and wherein said reference voltage generation circuit sets said reference voltage to a middle potential between said first potential and said second reference potential.

8.(Currently amended) ~~The~~ A physical quantity detection device ~~as claimed in claim 1,~~ further comprising:

an operational amplifier;

a first resistor connected between an inverting input of said operational amplifier and a first reference potential;

a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;

a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance;

a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier;

a third resistor;

another operational amplifier having an inverting input supplied with an output of said

operational amplifier through said third resistor, a non-inverting input of said another operational amplifier being supplied with said reference voltage; and

a fourth resistor disposed between an output terminal and inverting input of said another operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, and wherein said reference voltage generation circuit includes first and second voltage dividing resistors connected in series between said first and second reference potentials to generate a divided voltage as said reference voltage.

9. (Original) The physical quantity detection device as claimed in claim 8, further comprising an offset trimming resistor between said first reference potential and said inverting input of said another operational amplifier.

10. (Original) The physical quantity detection device as claimed in claim 8, further comprising an offset trimming resistor between said second reference potential and said inverting input of said another operational amplifier.

11. (Original) The physical quantity detection device as claimed in claim 8, further comprising:

fifth and sixth resistors connected between said first reference potential and said inverting input of said second operational amplifier;

seventh and eighth resistors connected between said inverting input of said another operational amplifier and said second reference potential, wherein said sixth and seventh resistors have temperature dependencies of resistance.

12. (Original) The physical quantity detection device as claimed in claim 11, wherein at least one of said fifth and eighth resistors has a trimming structure for compensating a temperature characteristic of offset of the output of said another operational amplifier.

13. (Currently amended) A physical quantity detection device comprising:

an operational amplifier;

a first resistor connected between an inverting input of said operational amplifier and a first reference potential;

a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;

a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance; and

a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a

temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, wherein if it is assumed that a sensitivity of said sensing element at a reference temperature is S_0 , a resistance of said sensing element at said reference temperature is R_0 , and a resistance of said feedback resistor at said reference temperature is R_{ts0} , then, it is represented that said sensitivity of said sensing element at a temperature t which is different from said reference temperature by T is $S(T)$, said resistance of said sensing element at t is $R(T)$, and said resistance of said feedback resistor at t is $R_{ts}(T)$, and $S(T)$, $R(T)$, and $R_{ts}(T)$ are further represented by:

$S(T) = S_0 \cdot (1 + \beta_1 \cdot T + \beta_2 \cdot T^2)$, $R(T) = R_0 \cdot (1 + \alpha_1 \cdot T + \alpha_2 \cdot T^2)$, and $R_{ts}(T) = R_{ts0} \cdot (1 + A_1 \cdot T + A_2 \cdot T^2)$, where said α_1 , α_2 , β_1 , β_2 , A_1 , and A_2 are temperature coefficients, and wherein said α_1 , α_2 , β_1 , β_2 , A_1 , and A_2 are determined so as to establish both $A_1 = \alpha_1 - \beta_1$ and $A_2 = \alpha_2 - \beta_2 - \beta_1 \cdot (\alpha_1 - \beta_1)$.

14. (Original) The physical quantity detection device as claimed in claim 1, wherein said reference voltage is determined such that said almost all of a current flowing through said first resistor flows into said second resistor.

15.(Currently amended) A physical quantity detection device comprising:
 an operational amplifier;
 a first resistor connected between an inverting input of said operational amplifier and a first reference potential;
 a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;
 a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistor resistance; and
 a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein said reference voltage generation circuit sets said reference voltage to a middle potential between said first potential and said second reference potential ~~includes a third and fourth resistors connected in series between said first and second reference potentials and generates a divided voltage as said reference voltage, and a temperature coefficient of said third resistor is substantially equal to a temperature coefficient of said fourth resistor.~~

16. (Previously amended) A physical quantity detection device comprising:
 an operational amplifier;
 a first resistor connected between an inverting input of said operational amplifier and a first reference potential;
 a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient

of resistance;

a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance;

a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity,

a third resistor;

another operational amplifier, an inverting input of said another operational amplifier being supplied with an output of said operational amplifier through said third resistor, a non-inverting input of said another operational amplifier being supplied with said reference voltage; and

a fourth resistor disposed between an output terminal and inverting input of said another operational amplifier.

17. (Original) The physical quantity detection device as claimed in claim 3, wherein said concentrations of impurity of said first and second resistors are from $0.8 \times 10^{19} \text{ cm}^{-3}$ to $4 \times 10^{19} \text{ cm}^{-3}$ and said concentration of impurity of said feedback resistor is from $2.5 \times 10^{17} \text{ cm}^{-3}$ to $5.5 \times 10^{17} \text{ cm}^{-3}$.

18. (Original) The physical quantity detection device as claimed in claim 17, wherein said concentrations of impurity of said first and second resistors are about $1 \times 10^{19} \text{ cm}^{-3}$, and said concentration of impurity of said feedback resistor is about $4 \times 10^{17} \text{ cm}^{-3}$.

19. (Currently amended) A physical quantity detection device comprising: an operational amplifier;

a first resistor connected between an inverting input of said operational amplifier and a first reference potential;

a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;

a feedback resistor being connected between said inverting input of said operational amplifier and an output of said operational amplifier and having a second temperature coefficient of resistance; and

a reference voltage generation circuit connected between said first and second reference potentials for generating a reference voltage directly supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, and wherein said reference voltage generation circuit sets said reference voltage to a middle potential between said first potential and said second reference potential.

20. (Previously presented) The physical quantity detection device as claimed in claim 19, wherein said reference voltage generation circuit includes third and fourth resistors connected in series between said first and second reference potentials to generate a divided voltage as said reference voltage.

21. (Previously presented) The physical quantity detection device as claimed in claim 20, wherein a temperature coefficient of resistance of said third resistor is substantially equal to a temperature coefficient of resistance of said fourth resistor so that said reference voltage can be kept constant irrespective of temperature variation.

Please add new claims as follows:

22.(New) A physical quantity detection device comprising:
an operational amplifier;

a first resistor connected between an inverting input of said operational amplifier and a first reference potential;

a second resistor connected between said inverting input of said operational amplifier and a second reference potential, said first and second resistors having a first temperature coefficient of resistance;

feedback resistor means for providing feedback of said operational amplifier, wherein said feedback resistor means is connected between said inverting input of said operational amplifier and an output of said operational amplifier and includes a plurality of resistor elements to have a feedback resistance and a second temperature coefficient of resistance; and

a reference voltage generation circuit generating a reference voltage supplied to a non-inverting input of said operational amplifier, at least one of said first and second resistors comprising a sensing element of which resistance varies on the basis of a physical quantity with a temperature coefficient of sensitivity, wherein a difference between said first temperature coefficient of resistance and said temperature coefficient of sensitivity is substantially equal to said second temperature coefficient of resistance, and wherein said reference voltage generation circuit sets said reference voltage to a middle potential between said first potential and said second reference potential.

23.(New) The physical quantity detection device as claimed in claim 22, wherein at least one of said resistor elements comprises a trimming structure in resistance.